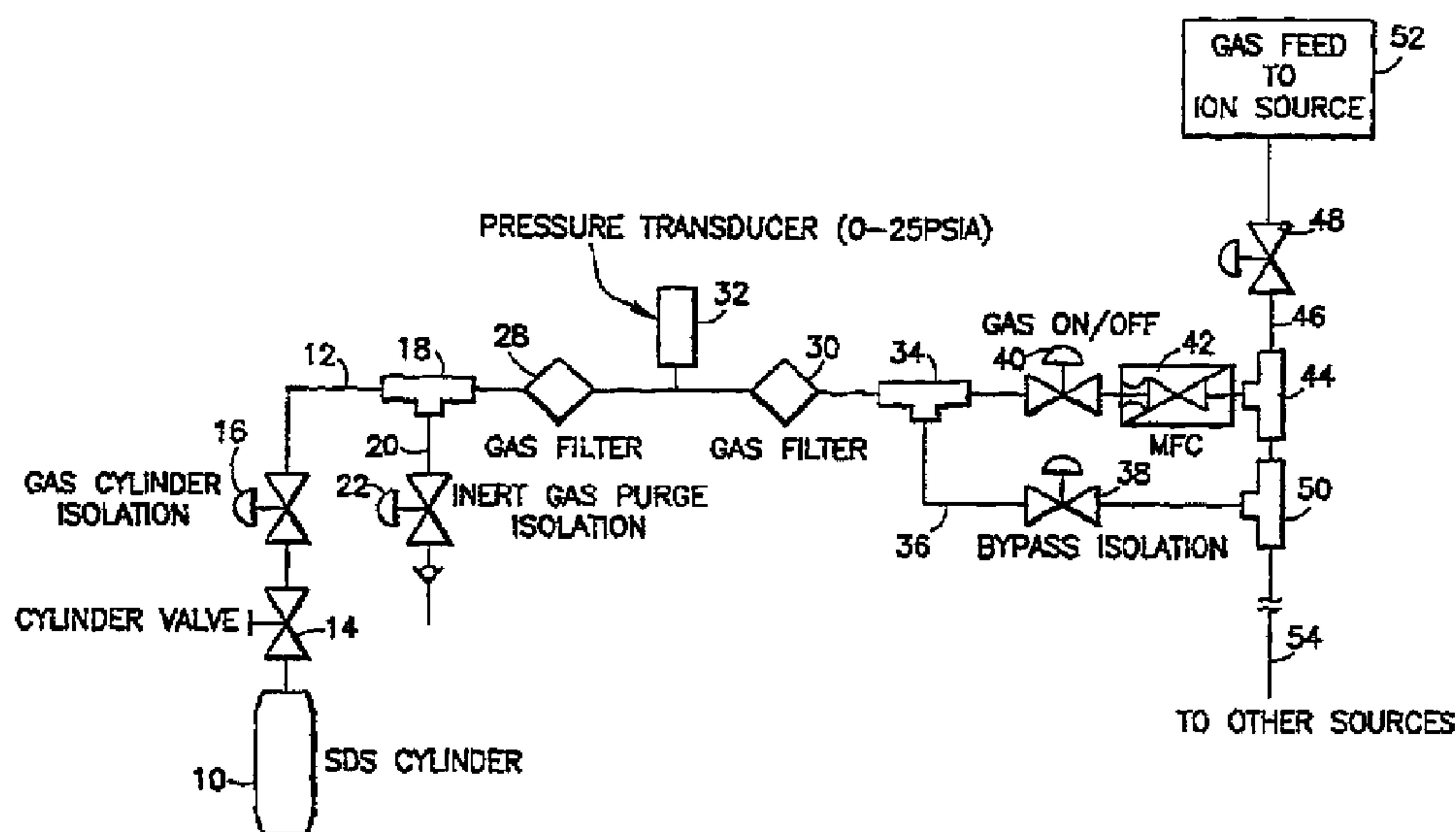




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(54) Titre : SYSTEME DE STOCKAGE ET DE DISTRIBUTION POUR COMPOSES GAZEUX
(54) Title: STORAGE AND DELIVERY SYSTEM FOR GASEOUS COMPOUNDS



(57) Abrégé/Abstract:

An adsorption-desorption apparatus (102), and process for storage and dispensing of a gas, e.g., hydride and halide gases, and organometallic Group V compounds, which is selectively dispensed by pressure differential desorption of the sorbate gas from the sorbent material. The sorbent material is preferably a material which is devoid of concentration of trace components such as water, metals and oxidic transition metal species which would significantly decompose the sorbate gas in apparatus (102).

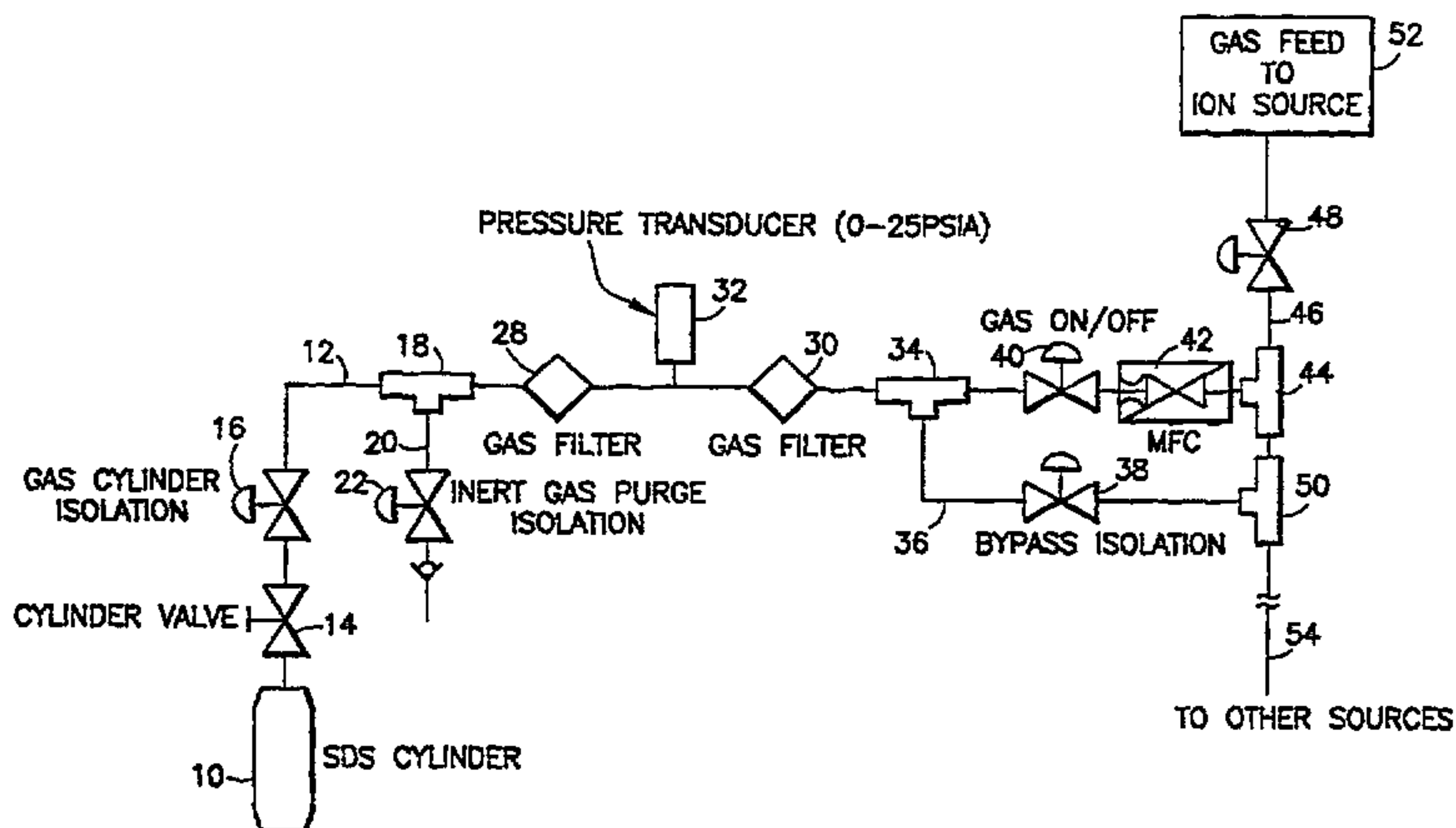


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(21) International Application Number: PCT/US95/13040 (22) International Filing Date: 13 October 1995 (13.10.95) (30) Priority Data: 322,224 13 October 1994 (13.10.94) US (60) Parent Application or Grant (63) Related by Continuation US 322,224 (CIP) Filed on 13 October 1994 (13.10.94) (71) Applicant (for all designated States except US): ATMI ECOSYS CORPORATION [US/US]; 617 River Oaks Parkway, San Jose, CA 95134-1907 (US). (72) Inventors; and (75) Inventors/Applicants (for US only): TOM, Glenn, M. [US/US]; 2 Powder Horn Lane, New Milford, CT 06776 (US). MCMANUS, James, V. [US/US]; 25 Padanaram Road, Danbury, CT 06811 (US). (74) Agent: HULTQUIST, Steven, J.; Intellectual Property/Technology Law, P.O. Box 14329, Research Triangle Park, NC 27709 (US).		(81) Designated States: AM, AU, BB, BG, BR, BY, CA, CN, CZ, EE, FI, GE, HU, JP, KE, KG, KP, KR, KZ, LK, LR, LT, LV, MD, MG, MN, MW, MX, NO, NZ, PL, RO, RU, SD, SG, SI, SK, TJ, TT, UA, US, UZ, VN, European patent (AT, BE, CH, DE, DK, ES, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, ML, MR, NE, SN, TD, TG), ARIPO patent (KE, MW, SD, SZ, UG). Published With international search report. With amended claims.

(54) Title: STORAGE AND DELIVERY SYSTEM FOR GASEOUS COMPOUNDS**(57) Abstract**

An adsorption-desorption apparatus (102), and process for storage and dispensing of a gas, e.g., hydride and halide gases, and organometallic Group V compounds, which is selectively dispensed by pressure differential desorption of the sorbate gas from the sorbent material. The sorbent material is preferably a material which is devoid of concentration of trace components such as water, metals and oxidic transition metal species which would significantly decompose the sorbate gas in apparatus (102).

STORAGE AND DELIVERY SYSTEM FOR GASEOUS COMPOUNDS.

5

Description**Field of the Invention**

10 This invention relates generally to storage and dispensing systems for the selective dispensing of gaseous reagents comprising hydride and halide gases, from a vessel or storage container in which the hydride and/or halide gas component(s) are held in sorptive relationship to a solid sorbent medium, and are desorptively released from the sorbent medium in the dispensing operation.

15

Description of the Related Art

20 In the manufacture of semiconductor materials and devices, and in various other industrial processes and applications, there is a need for a reliable source of hydridic and halidic gases. Many of such gases, including for example silane, germane, ammonia, phosphine, arsine, diborane, stibine, hydrogen sulfide, hydrogen selenide, hydrogen telluride, and corresponding and other halide (chlorine, bromine, iodine, and fluorine) compounds, as a result of toxicity and safety considerations, must be carefully stored and handled in the industrial process facility.

25

30 The gaseous hydrides arsine (AsH_3) and phosphine (PH_3) are commonly used as sources of arsenic (As) and phosphorous (P) in ion implantation. Due to their extreme toxicity and high vapor pressure, their use, transportation and storage raise significant safety concerns for the semiconductor industry. Ion implantation systems typically use dilute mixtures of AsH_3 and PH_3 at pressures as high as 1500 psig. A catastrophic release of these high pressure cylinders could pose a serious injury potential and even death to fab workers.

35

Based on these considerations, the ion implant user must choose between solid or gas sources for arsenic and phosphorous species. Switching from As to P on an implanter with solid sources can take as long as 90 minutes. The same species change requires only 15 minutes with gas sources. However, arsine (AsH_3) and phosphine (PH_3), the two most commonly used source gases, are highly toxic. Their use has recently been the focus of widespread attention due to the safety aspects of handling and processing these gases. Many ion implantation systems utilize hydride gas sources supplied as dilute mixtures (10-15%), in either 0.44 L or 2.3 L cylinders at pressures of 400 - 1800 psig. It is the concern over the pressure-driven release of the gases from cylinders that has prompted users to investigate safer alternatives.

U.S. Patent 4,744,221 issued May 17, 1988 to Karl O. Knollmueller discloses a method of storing and subsequently delivering arsine, by contacting arsine at a temperature of from about -30°C to about $+30^\circ\text{C}$ with a zeolite of pore size in the range of from about 5 to about 15 Angstroms to adsorb arsine on the zeolite, and then dispensing the arsine by heating the zeolite to an elevated temperature of up to about 175°C for sufficient time to release the arsine from the zeolite material.

The method disclosed in the Knollmueller patent is disadvantageous in that it requires the provision of heating means for the zeolite material, which must be constructed and arranged to heat the zeolite to sufficient temperature to desorb the previously sorbed arsine from the zeolite in the desired quantity.

The use of a heating jacket or other means exterior to the vessel holding the arsine-bearing zeolite is problematic in that the vessel typically has a significant heat capacity, and therefore introduces a significant lag time to the dispensing operation. Further, heating of arsine causes it to decompose, resulting in the formation of hydrogen gas, which introduces an explosive hazard into the process

system. Additionally, such thermally-mediated decomposition of arsine effects substantial increase in gas pressure in the process system, which may be extremely disadvantageous from the standpoint of system life and operating efficiency.

5

The provision of interiorly disposed heating coil or other heating elements in the zeolite bed itself is problematic since it is difficult with such means to uniformly heat the zeolite bed to achieve the desired uniformity of arsine gas release.

10

The use of heated carrier gas streams passed through the bed of zeolite in its containment vessel may overcome the foregoing deficiencies, but the temperatures necessary to achieve the heated carrier gas desorption of arsine may be undesirably high or otherwise unsuitable for the end use of the arsine gas, so that cooling or other treatment is required to condition the dispensed gas for ultimate use.

15

The present invention contemplates a gas storage and dispensing system, for the storage and dispensing of hydridic and halidic gases, which overcomes the above-discussed disadvantages of the method disclosed in the Knollmueller patent.

20

The system of the invention is adapted for storage and dispensing of hydridic and halidic gases and is selectively operable at ambient temperature levels, but is able to effectively utilize the high storage (sorptive) capacity of zeolite materials.

25

SUMMARY OF THE INVENTION

30

The present invention contemplates an adsorption-desorption apparatus, for storage and dispensing of a gas, e.g., a gas selected from the group consisting of hydride gases, halide gases, and organometallic Group V compounds, such apparatus comprising:

35

a storage and dispensing vessel constructed and arranged for holding a solid-phase physical sorbent medium, and for selectively flowing gas into and out of said vessel;

5 a solid-phase physical sorbent medium disposed in said storage and dispensing vessel at an interior gas pressure;

a sorbate gas physically adsorbed on said solid-phase physical sorbent medium;

10

a dispensing assembly coupled in gas flow communication with the storage and dispensing vessel, and constructed and arranged to provide, exteriorly of said storage and dispensing vessel, a pressure below said interior pressure, to effect desorption of sorbate gas from the solid-phase physical sorbent medium, and gas flow of desorbed gas through the dispensing assembly;

15

wherein the solid-phase physical sorbent medium is devoid of trace components selected from the group consisting of water, metals, and oxidic transition metal species (e.g., oxides, sulfites and/or nitrates) sufficient in concentration to decompose the sorbate gas in said storage and dispensing vessel.

20

In such apparatus, the solid-phase physical sorbent medium contains less than 350, preferably less than 100, more preferably less than 10, and most preferably less than 1, parts-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

25

30

In the apparatus of the invention, the solid-phase physical sorbent medium concentration of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium, desirably is insufficient

to decompose more than 5%, and preferably more than 1% by weight of the sorbate gas after 1 year at 25°C and said interior pressure.

5 In another aspect, the present invention relates to an adsorption-desorption apparatus, for storage and dispensing of a gas, e.g., a gas selected from the group consisting of hydride gases, halide gases, and organometallic Group V compounds, said apparatus comprising:

10 a storage and dispensing vessel constructed and arranged for holding a solid-phase physical sorbent medium, and for selectively flowing gas into and out of said vessel;

15 a solid-phase physical sorbent medium disposed in said storage and dispensing vessel at an interior gas pressure;

a sorbate gas physically adsorbed on said solid-phase physical sorbent medium;

20 a dispensing assembly coupled in gas flow communication with the storage and dispensing vessel, and constructed and arranged to provide, exteriorly of said storage and dispensing vessel, a pressure below said interior pressure, to effect desorption of sorbate gas from the solid-phase physical sorbent medium, and gas flow of
25 desorbed gas through the dispensing assembly;

30 wherein the solid-phase physical sorbent medium concentration of trace components selected from the group consisting of water, metals, and oxidic transition metal species, based on the weight of the physical sorbent medium, is insufficient to cause decomposition of the sorbate gas resulting in more than a 25%, and preferably more than a 10% rise in interior pressure after 1 week at 25°C in said storage and dispensing vessel.

6

In such apparatus, the solid-phase physical sorbent medium desirably contains less than 350, preferably less than 100, more preferably less than 10, and most preferably less than 1, part(s)-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

10 Still another aspect of the invention relates to an adsorption-desorption apparatus, for storage and dispensing of boron trifluoride, such apparatus comprising:

15 a storage and dispensing vessel constructed and arranged for holding a solid-phase physical sorbent medium having a sorptive affinity for boron trifluoride, and for selectively flowing boron trifluoride into and out of said vessel;

20 a solid-phase physical sorbent medium having a sorptive affinity for boron trifluoride, disposed in said storage and dispensing vessel at an interior gas pressure;

boron trifluoride gas, physically adsorbed on said solid-phase physical sorbent medium; and

25 a dispensing assembly coupled in gas flow communication with the storage and dispensing vessel, and constructed and arranged to provide, exteriorly of said storage and dispensing vessel, a pressure below said interior pressure, to effect desorption of boron trifluoride gas from the solid-phase physical sorbent medium, and gas flow of desorbed boron trifluoride gas through the dispensing
30 assembly.

Although generally preferred to operate solely by pressure differential, in respect of the sorption and desorption of the gas to be subsequently dispensed, the system of the invention may in some
35 instances advantageously employ a heater operatively arranged in

relation to the storage and dispensing vessel for selective heating of the solid-phase physical sorbent medium, to effect thermally-enhanced desorption of the sorbate gas from the solid-phase physical sorbent medium.

5

A preferred solid-phase physical sorbent medium comprises a crystalline aluminosilicate composition, e.g., with a pore size in the range of from about 4 to about 13 Å, although crystalline aluminosilicate compositions having larger pores, e.g., so-called mesopore compositions with a pore size in the range of from about 20 to about 40 Å are also potentially usefully employed in the broad practice of the invention. Examples of such crystalline aluminosilicate compositions include 5A molecular sieve, and preferably a binderless molecular sieve. Although molecular sieve materials such as crystalline aluminosilicates and carbon molecular sieves are preferred in many instances, the solid-phase physical sorbent medium may usefully comprise other materials such as silica, alumina, macroreticulate polymers, kieselguhr, carbon, etc. The sorbent materials may be suitably processed or treated to ensure that they are devoid of trace components which deleteriously affect the performance of the gas storage and dispensing system. For example, carbon sorbents may be subjected to washing treatment, e.g., with hydrofluoric acid, to render them sufficiently free of trace components such as metals and oxidic transition metal species. Potentially useful carbon materials include so-called bead activated carbon of highly uniform spherical particle shape, e.g., BAC-MP, BAC-LP, and BAC-G-70R, available from Kreha Corporation of America, New York, NY.

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The apparatus of the invention may be constructed with a solid-phase physical sorbent medium being present in the storage and dispensing vessel together with a chemisorbent material having a sorptive affinity for contaminants, e.g., decomposition products, of the sorbate gas therein. Such chemisorbent material may for example have a sorptive affinity for non-inert atmospheric gases. Examples of potentially suitable chemisorbent materials include a scavenger for

30

35

such contaminants, such as a scavenger selected from the group consisting of:

5 (A) scavengers including a support having associated therewith, but not covalently bonded thereto, a compound which in the presence of such contaminant provides an anion which is reactive to effect the removal of such contaminant, said compound being selected from one or more members of the group consisting of:

10 (i) carbanion source compounds whose corresponding protonated carbanion compounds have a pK_a value of from about 22 to about 36; and

15 (ii) anion source compounds formed by reaction of said carbanion source compounds with the sorbate gas; and

(B) scavengers comprising:

20 (i) an inert support having a surface area in the range of from about 50 to about 1000 square meters per gram, and thermally stable up to at least about 250° C; and

25 (ii) an active scavenging species, present on the support at a concentration of from about 0.01 to about 1.0 moles per liter of support, and formed by the deposition on the support of a Group IA metal selected from sodium, potassium, rubidium, and cesium and their mixtures and alloys and pyrolysis thereof on said support.
30

By way of an example, such chemisorbent material may advantageously comprise a scavenger component selected from the group consisting of: trityllithium and potassium arsenide.

In respect of such chemisorbent materials for contaminants of the sorbate gas to be dispensed, any of a wide variety of scavengers or chemisorbent materials may be employed, including scavenger compositions of the types disclosed and claimed in U.S. Patent 5 4,761,395 issued August 2, 1988 to Glenn M. Tom, et al.; U.S. Patent 5,385,689 (08/084,414) issued January 31, 1995; and U.S. Patent 5,531,971 (08/322,315 division of 08/084,414) issued July 2, 1996.

10 The chemisorbent material when employed may be utilized as a separate bed in gas communication with the bed of physical adsorbent, or alternatively the chemisorbent may be dispersed randomly or selectively throughout a bed of physical adsorbent material in the storage and dispensing vessel.

15 The invention in another aspect relates to an ion implantation system, comprising a reagent source for reagent source material and an ion implantation apparatus coupled in gas flow communication with such reagent source, and wherein the reagent source is of a type described hereinabove.

20

The present invention relates in still another aspect to a process for supplying a gas reagent selected from the group consisting of hydride gases, halide gases, and organometallic Group V compounds, such process comprising:

25

providing a storage and dispensing vessel containing a solid-phase physical sorbent medium having a physically sorptive affinity for said gas reagent;

30

physically sorptively loading on said solid-phase physical sorbent medium a sorbate gas selected from the group consisting of hydride gases and boron halide gases, to yield a sorbate gas-loaded physical sorbent medium; and

10

desorbing sorbate gas from the sorbate gas-loaded physical sorbent medium, by reduced pressure desorption, for dispensing thereof;

5 wherein the solid-phase physical sorbent medium is devoid of trace components selected from the group consisting of water, metals and oxidic transition metal species in a sufficient concentration to decompose the sorbate gas in said storage and dispensing vessel.

10 In a further particular aspect, the invention relates to an adsorption-desorption process for storage and dispensing of boron trifluoride, comprising:

15 providing a storage and dispensing vessel containing a solid-phase physical sorbent medium having a physically sorptive affinity for boron trifluoride;

20 physically sorptively loading boron trifluoride on said solid-phase physical sorbent medium, to yield a boron trifluoride-loaded physical sorbent medium; and

25 selectively desorbing boron trifluoride from the boron trifluoride-loaded physical sorbent medium, by reduced pressure desorption, for dispensing thereof.

30 Another apparatus aspect of the present invention relates to an adsorption-desorption apparatus, for storage and dispensing of a gas sorbable on a solid-phase physical sorbent medium, such apparatus comprising:

a storage and dispensing vessel constructed and arranged for holding a solid-phase physical sorbent medium, and for selectively flowing gas into and out of said vessel;

a solid-phase physical sorbent medium disposed in the storage and dispensing vessel at an interior gas pressure;

5 a sorbate gas physically adsorbed on the solid-phase physical sorbent medium;

10 a dispensing assembly coupled in gas flow communication with the storage and dispensing vessel, and constructed and arranged to provide, exteriorly of the storage and dispensing vessel, a pressure below said interior pressure, to effect desorption of sorbate gas from the solid-phase physical sorbent medium, and gas flow of desorbed gas through the dispensing assembly;

15 a cryopump coupled to the dispensing assembly for pressurizing the desorbed gas and discharging the resultingly pressurized gas.

20 In a further process aspect, the present invention relates to a process for storage and dispensing of a gas sorbable on a solid-phase physical sorbent medium, such process comprising:

providing a storage and dispensing vessel holding a solid-phase physical sorbent medium;

25 adsorbing such gas on the solid-phase physical sorbent medium;

30 establishing, exteriorly of the storage and dispensing vessel, a pressure below the interior pressure, to effect desorption of sorbate gas from the solid-phase physical sorbent medium, and flowing desorbed gas out of the storage and dispensing vessel;

cryopumping the desorbed gas from the storage and dispensing vessel to a predetermined pressure, wherein such

predetermined pressure is higher than the pressure of the desorbed gas flowed out of the storage and dispensing vessel.

5 Other aspects, features and embodiments of the invention will be more fully apparent from the ensuing disclosure and appended claims.

BRIEF DESCRIPTION OF THE DRAWINGS

10 Figure 1 shows a graph of the adsorption isotherm for arsine, as a plot of the arsine loading in grams arsine per liter of zeolite 5A, as a function of the log pressure in Torr.

15 Figure 2 shows a graph of the adsorption isotherm for arsine, as a plot of the arsine loading in grams phosphine per liter of zeolite 5A, as a function of the log pressure in Torr.

20 Figure 3 is a schematic representation of a storage and delivery system according to one embodiment of the invention.

Figure 4 is a delivery lifetime plot of arsine pressure, in Torr, as a function of hours of operation of the storage and delivery system apparatus.

25 Figure 5 is a plot of cylinder pressure, in Torr, as a function of time, in seconds, as well as a plot (on the right-hand y-axis) of temperature, in degrees Centigrade, as a function of time, in seconds, graphically showing the temperature and pressure rises during the experimental backfilling of a phosphine gas storage and delivery
30 system apparatus, with room air.

Figure 6 is a plot of arsine released, in grams, as a function of time, in seconds, for a standard cylinder of arsine, versus an arsine storage and delivery system apparatus, in simulation of a worst case
35 emission incident.

Figure 7 is a schematic perspective view of a cryopumping storage and delivery system apparatus according to a further embodiment of the invention.

Figure 8 is a graph of storage and delivery system cylinder pressure level, in psia, as a function of elapsed time, in minutes, for two molecular sieve sorbent materials of differing iron content.

DETAILED DESCRIPTION OF THE INVENTION, AND PREFERRED MODES OF CARRYING OUT SAME

The present invention provides a new atmospheric pressure storage and delivery system apparatus as a source gas supply means for applications such as ion implantation of hydride and halide gases, and organometallic Group V compounds, e.g., arsine, phosphine, chlorine, NF_3 , BF_3 , BCl_3 , diborane (B_2H_6 and its deuterium analog, B_2D_6), HCl , HBr , HF , HI , tungsten hexafluoride, and $(\text{CH}_3)_3\text{Sb}$. The new gas source system is comprised of a leak-tight gas vessel, such as a gas cylinder, containing the gas to be dispensed, e.g., arsine or phosphine, adsorbed into a sorbent material comprising zeolite or other suitable physical adsorbent material. In the case of arsine and phosphine, the zeolite reduces the vapor pressure of the arsine and phosphine to ≤ 1 atmosphere.

Since the storage and delivery system is initially at atmospheric pressure, the release rate is controlled primarily by diffusion instead of a pressure differential. Inadvertent releases from the storage and delivery system have been measured and result in exposure concentrations to $< 1/2$ IDLH. Release rate comparisons of the storage and delivery system to standard cylinders are more fully discussed hereinafter, and demonstrate that the storage and delivery system apparatus and method of the present invention is about 1×10^5 safer than compressed gas sources.

While the invention is discussed primarily hereinafter in terms of the storage and delivery of arsine and phosphine gases, it will be recognized that the utility of the present invention is not thus limited, but rather extends to and is inclusive of various other hydride and halide gases, as for example silane, diborane, arsine, phosphine, chlorine, BCl₃, BF₃, B₂D₆, tungsten hexafluoride, hydrogen fluoride, hydrogen chloride, hydrogen iodide, hydrogen bromide, germane, ammonia, stibine, hydrogen sulfide, hydrogen selenide, hydrogen telluride, and corresponding and other halide (chlorine, bromine, iodine, and fluorine) gaseous compounds such as NF₃, and organometallic Group V compounds such as (CH₃)₃Sb.

The novel means and method of the present invention for storing and delivering gaseous arsine and phosphine at ≤ 0 psig greatly reduces the hazard posed by these gases. The technique involves the adsorption of these gases into a physical adsorbent such as, for example, zeolite 5A. By adsorbing the gas into a zeolite or other suitable solid physical sorbent, the vapor pressure of the gas can be reduced to ≤ 0 psig. The release potential from this system is greatly reduced as the driving force of pressure is eliminated. Collectively, the storage and delivery system may usefully consist of a standard gas cylinder and cylinder valve, loaded with dehydrated zeolite 5A. The cylinder is subsequently filled to 1 atmosphere with the hydride gas. Although primarily disclosed hereinafter in reference to zeolites, the invention is broadly applicable to the usage of a wide variety of other physical sorbent materials, such as kieselguhr, silica, alumina, macroreticulate polymers (e.g., Amberlite resins, available from Rohm & Haas Company, Philadelphia, PA), carbon (e.g., bead activated carbon), etc.

Zeolites are microporous crystalline aluminosilicates of alkali or alkaline earth elements represented by following stoichiometry:



where x and y are integers with $y/x =$ to or greater than 1, n is the valence of the cation M and z is the number of water molecules in each unit cell. Zeolite 5A has $\sim 2.5 \times 10^{21}$ hydride adsorption sites per gram. A liter of zeolite will adsorb 100 grams of phosphine and 220 grams of arsine at 25°C and 1 atmosphere. Figures 1 and 2 show the adsorption isotherms for arsine and phosphine, respectively.

These isotherms show vapor pressure as a function of adsorbed hydride for a 1 liter cylinder. The isotherms are useful in determining the amount of deliverable hydride gas. As seen from the isotherms, roughly 50% of the hydride is adsorbed between 50-760 Torr. This is the amount of hydride that can practically be delivered by the respective storage and delivery systems.

Gas flow from the storage and delivery system is established using the existing pressure differential between the storage and delivery system and the ion implant vacuum chamber or other downstream use locus. Utilizing a device such as a mass flow controller, a constant flow can be achieved as the sorbent container pressure decreases.

An appropriate delivery system for a zeolite storage system according to the invention is shown in Figure 3.

In the schematic storage and delivery system shown in Figure 3, a gas storage cylinder 10 is provided which may be filled with a bed of suitable physical adsorbent material, e.g., a zeolite sorbent or other suitable physical adsorbent medium of a type as more fully described hereinabove. The gas cylinder 10 is provided therein with the physical adsorbent bearing a physically adsorbed gas component, or components, such as arsine or phosphine.

16

The cylinder 10 is connected to a manifold 12, having disposed therein a cylinder valve 14 for controllably releasing gas from cylinder 10, upstream of a gas cylinder isolation valve 16, which may be selectively actuated to close cylinder 10 to communication with the manifold 12.

The manifold has a branch fitting 18 therein, by means of which the manifold 12 is coupled in gas flow communication with a branch purge line 20 having inert gas purge isolation valve 22 therein, whereby the manifold may be purged with inert gas, prior to active operation delivery of gas from cylinder 10.

Downstream from the fitting 18, the manifold contains two successive gas filters 28 and 30, intermediate of which is disposed a pressure transducer 32 which may, for example, have a pressure operating range of from about 0 to about 25 psia.

The manifold 12 is connected downstream of gas filter 30 with a branch fitting 34 to which is coupled a bypass conduit 36 having bypass isolation valve 38 therein. The manifold 12 downstream of fitting 34 has a gas flow on-off valve 40 therein, downstream of which is disposed a mass flow controller 42 for controllably adjusting the flow rate of the hydride or halite gas dispensed through manifold 12. At its terminus downstream of mass flow controller 42, the manifold 12 is connected by coupling fitting 44 to dispensing line 46 filing flow control valve 48 therein, and also being coupled in gas flow communication with bypass line 36 via coupling fitting 50. The discharge line 46 is as shown joined to an ion source generating means, schematically shown as element 52. The other end 54 of discharge line 46 may be suitably coupled in gas flow communication with another gas dispensing means, as desirable or necessary in a given end use application of the Figure 3 storage and delivery system apparatus.

Figure 4. shows the delivery lifetime of a 4X molecular sieve (2.35 liters) in an arsine storage and delivery system apparatus to be ~1000 hr. at a flow rate of 1 sccm.

5 The lifetime test was conducted using a storage and delivery system apparatus similar to that schematically shown in Figure 3.

10 In addition to the safety advantages, the zeolite storage technology of the present invention allows for a greater quantity of delivered gas. Table 1 below shows a comparison of delivered hydride from typical high pressure sources to that of the storage and delivery system.

15

Table 1

Delivery comparison of storage and delivery system cylinders to a standard high pressure cylinder (grams delivered)

20

25

Gas	400 PSIG 15% storage/delivery system	440 ml storage/delivery system	2.3 Liter
Arsine	6	40	225
Phosphine	3	18	105

30

Since approximately 5-20 times as much hydride is delivered by the storage and delivery system than by standard cylinders, fewer cylinder changes are required, thereby yielding enhanced productivity of the implant tool. Additionally, since most accidents with gases occur during cylinder changes, safety is further improved.

35

Since the storage and delivery system operates in the sub-atmospheric regime, the safety aspects related to an accidental incursion of air into a phosphine storage and delivery system cylinder was investigated. Phosphine spontaneously reacts with air as shown in the following equation:

40



$$\Delta H_f \text{ of } \text{P}_4\text{O}_{10} = -720 \text{ Kcal/mole}$$

5 A threshold concern and intuitive expectation is that the excessive
 heat of reaction would cause a large pressure excursion or even a
 detonation in the cylinder. However, it has been determined that the
 event of ingressing air is of a manageable character since most of the
 resultingly generated heat will be adsorbed by the zeolite substrate.
 10 Figure 5 shows the temperature and pressure rise during the
 experimental backfilling of a 0.5 liter phosphine storage and delivery
 system with room air, as a plot of cylinder pressure, in Torr, as a
 function of time, in seconds.

15 In the Figure 5 system, the initial pressure of the phosphine storage
 and delivery system was 50 Torr. Upon backfilling, the reaction
 temperature was monitored with a thermocouple located inside the
 storage and delivery system cylinder. The reaction with air caused a
 temperature rise of 35°C inside the cylinder. The cylinder pressure
 20 was measured using a capacitance pressure transducer. The
 maximum pressure recorded was ~ 800 Torr. The pressure rise
 above 1 atmosphere is a result of the increased bed temperature.
 The experimental data left us to conclude that the air backfill of a
 partially used phosphine storage and delivery system is not a
 25 significant safety hazard. The arsine case was not investigated as
 arsine reacts slowly with air at room temperature.

Hydride release was measured in a storage and delivery
 system apparatus of the type shown in Figure 3 and described
 30 hereinabove. The emission rate of arsine from the storage and
 delivery system was measured and found to be 3.8 milligrams/minute.
 Although small, such rate was 3 orders of magnitude larger than that
 calculated from diffusion equations. It is suspected that the apparatus
 used in this experiment gave an erroneously high emission rate due
 35 to an eduction effect. Nonetheless, this experiment gives a worst

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case emission rate that is still 10^{-5} times less than a standard high pressure cylinder. Figure 6. shows the emission rate of a standard gas cylinder versus an arsine storage and delivery system.

5 The purity of the arsine and phosphine from the storage and delivery system of the instant invention is exceptional. The only significant impurity detected is H_2 . The hydrogen levels are found to vary between 10-1000 ppm. Since H_2 is currently used as a diluent in high pressure cylinders its presence is non-problematic in terms of operational efficacy of the storage and delivery system apparatus and method. Gas chromatography and mass spectroscopy have been used to verify the purity of the hydride.

15 The storage and delivery system-delivered arsine and phosphine is fully compatible with the ion implantation process. Yield analyses of wafers from split lots have been shown to be identical for those implanted with As and P from the storage and delivery system compared with those implanted with As and P from standard sources.

20 The storage and delivery system apparatus and method of the invention thus provide a significantly safer alternative to the current use of high pressure gas cylinders for the storage and dispensing of hydride and halide gases. The invention provides the capability to transport, store and deliver hydrides from a cylinder or other vessel at zero psig. The invention is based on the discovery that hydride and halide gases can be physically adsorbed into the microcavities of suitable support materials such as zeolites, thereby significantly reducing the pressure of gas for storage and dispensing purposes.

30 With only low level heating of the sorbent material in the practice of the present invention, by so-called thermally assisted delivery, it is possible to augment the delivery rate of the desorbing gas, so that flow rates of up to 500 sccm and higher are readily achievable. Nonetheless, high rates of gas delivery are achieved in the broad practice of the present invention with adiabatic operation.

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AMENDED SHEET

(no supplemental input of heat or thermal energy to the sorbate-laden sorbent medium), solely by the pressure differential existing between the sorbent vessel and the reduced pressure of the semiconductor (or other industrial or manufacturing) process, such as ion implantation, molecular beam epitaxy, and chemical vapor deposition.

The apparatus of the present invention may be readily provided in a unitary apparatus form, as disposed in a gas cabinet containing a multiplicity, e.g., three, sorbent vessels, each manifolded together for selective delivery of sorbate gas from one or more of such vessels. The cabinet may further include therein independent thermocouples, or other temperature sensing/monitoring equipment and components for preventing overheating of the vessels and/or other internal components of the gas cabinet in use thereof.

The cabinet may additionally include a fusible link heater element for selective augmentive heating of the vessels and sorbent therein; a sprinkler system; an exhaust heat sensor; a toxic gas monitor which functions to shut down the apparatus when toxic gas is sensed; a scrubber or bulk sorption device; and redundant pressure and temperature control means. With such a storage and delivery system apparatus, delivery rates of gas of 500 sccm at 15 psig are readily attainable.

In the preferred practice of the invention, the solid-phase physical sorbent medium is devoid of trace components selected from the group consisting of water, metals, and oxidic transition metal species in a concentration which is insufficient to decompose the sorbate gas in said storage and dispensing vessel. A highly advantageous sorbent medium of such type is commercially available from Zeochem Company (Louisville, KY) as Zeochem Binderless 5A sorbent, which is a synthetic calcium aluminosilicate of the formula $(\text{CaO} \cdot \text{Na}_2\text{O}) \cdot \text{Al}_2\text{O}_3 \cdot 2\text{SiO}_2 \cdot x\text{H}_2\text{O}$.

In this respect, it is to be noted that the significant presence in the sorbent material of any water, metals, or transition metal oxides tends to promote undesirably high levels of decomposition of the sorbate gas. In molecular sieves and other materials which lack such "contaminants" the sorbate gas degradation levels, and corresponding pressure levels are maintained at correspondingly low values. Concerning molecular sieve materials most specifically, a large number of such sorbents invariably contain clay or other mineralic binders which contain the aforementioned decomposition promoters, which undesirably degrade the performance of the storage and delivery system apparatus and method.

By way of example, the above-mentioned binderless Zeochem material has no detectable metallic impurities, while other conventional molecular sieve materials, e.g., Linde 5A zeolite has a substantial amount of iron therein. In consequence, the binderless zeolite exhibits decomposition levels which are on the order of about 1-2% of arsine (in an arsine storage and delivery system apparatus containing such zeolite) per year, while the Linde 5A zeolite exhibits decomposition levels of arsine which are on the order of a few tenths of a percent of the arsine per day. With the binderless zeolite, pressure increases in the sorbent material-containing vessel are less than 5% per week, while the Linde 5A zeolite (containing binder metal components) exhibits pressure rises of 9 psig (60%) per day in a corresponding storage and delivery system apparatus.

The solid-phase physical sorbent medium in the preferred practice of the invention therefore contains less than 350 parts-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium, more preferably less than 100 parts-per-million by weight, still more preferably less than 10 parts-per-million, and most preferably no more than 1 part-per-million by weight of trace components selected from the group consisting of

water and oxidic transition metal species, based on the weight of the physical sorbent medium.

5 Correspondingly, the solid-phase physical sorbent medium concentration of trace components selected from the group consisting of water and oxidic transition metal species (e.g., oxides, sulfites and nitrates), based on the weight of the physical sorbent medium, preferably is insufficient to decompose more than 5% by weight of the sorbate gas after 1 year at 25°C and said interior pressure.

10

In some applications, it is desired to provide gases deriving from a storage and delivery system apparatus at a higher-than-discharge pressure from the storage and delivery system sorbent-containing vessel. In such instances, venturi pumps may be employed which raise the pressure of the supplied gas to a selected pressure level above that at the cylinder head (of the cylinder containing the sorbent binding the gas being dispensed). Although such venturi pumping arrangements yield the dispensed gas at the selected higher pressure level, such arrangements nonetheless entail dilution of the gas being dispensed with a carrier gas, since the carrier gas is entrained with the dispensed gas from the cylinder.

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Such dilution effect represents a significant constraint on the overall process system, in instances where neat gas of high purity is desired from the storage and delivery system apparatus. Mechanical pumps may be used in place of venturi pumping means, but mechanical pumps entail the disadvantage of a significant number of moving parts, which can cause problems associated with the formation of particulates in the pump and/or entrainment of lubricants.

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In such instances, where the gas supplied by the storage and delivery system apparatus is desired to be furnished at high pressure in a high purity, neat condition, the provision of a cryopumping assembly in the storage and delivery system apparatus may be advantageous.

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Figure 7 is a schematic perspective view of such a cryopumping storage and delivery system apparatus 100, according to a further embodiment of the invention.

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In the cryopumping system, the main cylinder 102 contains a suitable sorbent material (not shown), e.g., molecular sieve, having loaded thereon a suitable sorbate gas species to be subsequently dispensed, and is equipped with a valve head assembly 104 including main cylinder valve 106, which is in the "off" position at the start of the dispensing process.

10

The valve head 104 is coupled to conduit 108 containing isolation valve 110, mass flow controller 112, isolation valve 114, and cryopump 116. Conduit 108 is in turn coupled to conduit 109 containing isolation valves 118 and 122 and product dispensing regulator assembly 130 having discharge port 134 coupleable to a downstream process system. Joined to the conduit 109 is a medium pressure storage vessel 120.

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The cryopump 116 coupled to conduit 108 is provided with a liquid nitrogen (or other suitable cryogenic liquid or fluid) inlet 128 and a liquid nitrogen outlet 126, with a liquid cryogen flow path being provided intermediate the inlet 128 and the outlet 126 which is circumscribed by heating elements 124 as shown. The liquid cryogen inlet and outlet of the cryopump may be suitably joined to a source of liquid cryogen, as for example a cryogenic air separation installation or a cryogenic cylinder source of liquid nitrogen or other coolant. The cryopump thereby forms a cryotrap apparatus. The outlet of the cryopump thus is provided with an isolation valve 122, and the medium pressure cylinder 120 is isolatable by means of the isolation valve 122.

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A pressure transducer 111 is provided in conduit 108 and is coupled in pressure monitoring relationship to cylinder 102 for

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monitoring of pressure in the cylinder and responsively adjusting the isolation valve 118.

5 The operation of the storage and delivery system shown schematically in Figure 7 is illustrated below with reference to silane as the gas sorbed on the sorbent in cylinder 102 and to be delivered at suitable elevated pressure, and nitrogen as the cryogen to be employed as the working fluid in the cryopump 116. Silane has a boiling point of -111.5 degrees Centigrade and a melting point of 185
10 degrees Centigrade, and nitrogen has a boiling point of -195.8 degrees Centigrade.

 Silane has been selected for illustration purposes since it is relatively difficult to deliver at suitably elevated pressure (in relation to
15 other hydridic gases such as arsine which have higher boiling and freezing points, and thus may be more easily cryopumped with less cryogenic cooling being required).

 If at the outset valves 110, 114, and 106 are open, with valves
20 118 and 122 being closed and under vacuum, and the temperature in the cryogenic pump is lowered to liquid nitrogen temperatures, silane will condense and freeze in the cryopump, even if relatively low internal pressures exist in the supply cylinder 102.

25 The mass flow controller 112 allows for accurate determination of the quantity of gas being transferred to the cryopump 116. Such accurate determination is important because overpressurization of the cryopump is desirably avoided. Under such operating conditions, silane will be above its critical temperature so that the ultimate
30 pressure in the cryopump can potentially become very high.

 After the correct amount of gas has been transferred to the cryopump 116, the valves 110 and 114 are closed. The condensed silane then is warmed to near ambient temperatures. The heating is
35 carried out by the heating means 124, which in the embodiment

5 shown comprise band heaters but could be any suitable heating means appropriate for such service. The silane gas does not thereby have to be heated to high temperatures, and the stability and purity of the product gas to be dispensed is thereby enhanced, since heating may result in the occurrence of degradation of the silane gas with consequent adverse effect on its purity and further stability.

10 The pressure of the silane gas after the warm-up in the cryopump may become significantly elevated, and effectively the gas thereby has become compressed, in a high purity state, and without exposure to a mechanical pump with many moving parts which may otherwise result in contamination of the product gas.

15 The inventory of gases in the overall system may be quite low at this point, with most of the silane residing in the sorbent vessel, cylinder 102, at low pressure.

20 Opening valve 118 will then allow gas to flow into the medium pressure cylinder 120; if valve 122 is open, then product silane gas can flow to the downstream process through discharge port 134, as monitored by the monitoring means (e.g., flow pressure) associated with the regulator assembly 130. The regulator assembly 130 has associated pressure transducer 132 which may be operatively coupled in the overall system with the other valves and cryopump components so that the product gas is delivered at a selected pressure and volumetric flow rate.

30 Correspondingly, the various valves, mass flow controller, cryopump, transducers and regulator may be operatively interconnected in any suitable manner, e.g., with cycle timer, and process safety systems, to carry out the demand-based delivery of silane or other sorbate gases, in a readily controllable and reproducible manner.

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Accordingly, the operation of the system schematically shown in Figure 7 desirably is timed to avoid disruption to or interference with downstream process flows. Signals from the mass flow controller and pressure transducers in the cryopump and medium pressure tanks can be used in an automated process system. The cryopump can be cycled to move gases from the storage and delivery system to the medium pressure cylinder 120 to maintain a constant pressure at the outlet of the regulator.

10

EXAMPLE I

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Decomposition of arsine gas in a storage and delivery cylinder was comparatively evaluated for each of two molecular sieve sorbent materials: Linde 5A molecular sieve (Union Carbide Corporation, Danbury, Connecticut), hereinafter referred to as Sorbent A, and Zeochem 5A molecular sieve (Zeochem, Louisville, KY), hereinafter referred to as Sorbent B. Each of Sorbent A and Sorbent B are synthetic crystalline calcium aluminosilicates having 5 Angstrom pore size, but Sorbent A contains a clay binder whereas Sorbent B is binderless.

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Set out in Table II below is a quantitative analysis of the Sorbent A and Sorbent B showing the differences in composition thereof, where the part-per-million (ppm) concentrations listed are \pm 50%.

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Table II
Quantitative Analysis of Sorbent A and Sorbent B, in parts-
per-million (ppm)

		Sorbent A	Sorbent B
5	Aluminum	major ^a	major
	Barium	< 372	< 301
	Beryllium	< 372	< 301
	Calcium	major	major
	Cobalt	< 372	< 301
10	Chromium	< 372	< 301
	Copper	< 372	< 301
	Iron	3084	< 301
	Gallium	< 372	< 301
	Magnesium	556	< 301
15	Manganese	< 372	< 301
	Molybdenum	< 372	< 301
	Nickel	< 372	< 301
	Phosphorus	< 372	< 301
	Lead	< 372	< 301
20	Silicon	major	major
	Tin	< 372	< 301
	Strontium	< 372	< 301
	Titanium	< 372	< 301
	Vanadium	< 372	< 301
25	Zinc	< 372	< 301
	Zirconium	< 372	< 301
30	% Silicon	21.19	19.70
	% Aluminum	19.11	17.39
	% Calcium	7.21	7.45

^a major here referring to at least 5% by weight, based on the total weight of the molecular sieve

As shown by the data in Table II, Sorbent B contained trace amounts (defined here as amounts of less than about 500 ppm of the specified component) of all measured elements with the exception of the major components of the molecular sieve, calcium, aluminum, and silicon, while Sorbent A contained a significant amount of iron (3084 ppm) and slightly more than a trace amount of magnesium.

In the comparison test of the two sorbent materials, each of identical gas cylinders was filled with a respective sieve material (Sorbent A in a first cylinder and Sorbent B in a second cylinder), and the sieve materials in each of the cylinders was loaded with a same amount of arsine gas. After the loading of the sieve materials in the respective cylinders, the pressures in each of the cylinders was monitored for pressure rise due to decomposition of arsine by the reaction $\text{As} \rightarrow \text{As} + 1.5 \text{H}_2$, since hydrogen is not adsorbed by the molecular sieves. Such monitoring took place at constant temperature.

The resulting pressure history as a function of time is shown in the graph of Figure 8, in which the pressure in psia is plotted as a function of elapsed time, in minutes. As shown by the Figure, curve A, showing the pressure behavior of the gas in the cylinder containing Sorbent A, after 250 hours rose to approximately 37.5 psia, while curve B, showing the pressure behavior of the gas in the cylinder containing Sorbent B, shows no pressure rise over the same period of time of the test.

The performance differences exhibited by the respective Sorbents A and B is striking, for the fact that while otherwise compositionally equivalent, the fact of the more-than-trace concentration of iron in Sorbent A led to substantially increased pressure due to the decomposition of arsine in the cylinder containing Sorbent A, while Sorbent B maintained the arsine in an undecomposed state, with no formation of hydrogen being observed in respect of pressure increase.

Accordingly, it is a significant discovery that the decomposition of hydridic gases such as arsine, phosphine, etc., can be suppressed by the provision of sorbent materials which are devoid of more than trace amounts of contaminants such as iron, which are conventionally present in commercially available molecular sieves and other sorbent materials comprising mineralic or clay-based binders, which have been incorporated in the sorbent composition for enhancing the structural stability and integrity of the sorbent material.

INDUSTRIAL APPLICABILITY

The present invention has utility in the manufacture of semiconductor materials and devices, and in other gas-consuming process operations, where it provides a reliable "on demand" source of gas, e.g., hydride gases, halide gases, and gaseous organometallic Group V compounds, including, for example, silane, diborane, germane, ammonia, phosphine, arsine, stibine, hydrogen sulfide, hydrogen selenide, hydrogen telluride, boron trifluoride, tungsten hexafluoride, chlorine, hydrogen chloride, hydrogen bromide, hydrogen iodide, and hydrogen fluoride.

By providing an economical and reliable source of such gases, in which the gas is safely held at relatively low pressure in the adsorbed state on a sorbent medium, and subsequently is easily dispensed to the point of use of the gas, the present invention avoids the hazards and gas handling problems associated with the use of conventional high pressure gas cylinders.

CLAIMS:

1. An adsorption-desorption apparatus, for storage and dispensing of a gas, said apparatus comprising:

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a storage and dispensing vessel constructed and arranged for holding a solid-phase physical sorbent medium, and for selectively flowing gas into and out of said vessel;

10

a solid-phase physical sorbent medium disposed in said storage and dispensing vessel at an interior gas pressure;

a sorbate gas physically adsorbed on said solid-phase physical sorbent medium;

15

a dispensing assembly coupled in gas flow communication with the storage and dispensing vessel, and constructed and arranged to provide, exteriorly of said storage and dispensing vessel, a pressure below said interior pressure, to effect desorption of at least a portion of said sorbate gas from the solid-phase physical sorbent medium and yield desorbed gas, and gas flow of said desorbed gas through the dispensing assembly;

20

wherein any water, metals, and oxidic transition metal species present on the solid-phase physical sorbent medium are at a concentration which is insufficient to decompose more than 5% by weight of the sorbate gas in said storage and dispensing vessel after 1 year at 25°C at said interior gas pressure.

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2. Apparatus according to claim 1, wherein the solid-phase physical sorbent medium contains less than 350 parts-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

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3. Apparatus according to claim 1, wherein the solid-phase physical sorbent medium contains less than 100 parts-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

4. Apparatus according to claim 1, wherein the solid-phase physical sorbent medium contains no more than 1 part-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

5. Apparatus according to claim 1, wherein the solid-phase physical sorbent medium comprises a binderless physical sorbent medium.

6. Apparatus according to claim 1, wherein the oxidic transition metal species are selected from the group consisting of oxides, sulfites and nitrates.

7. Apparatus according to claim 1, wherein the sorbate gas is a hydride gas.

8. Apparatus according to claim 1, wherein the sorbate gas is selected from the group consisting of silane, diborane, arsine, phosphine, chlorine, BCl_3 , BF_3 , B_2D_6 , tungsten hexafluoride, $(\text{CH}_3)_3\text{Sb}$, hydrogen fluoride, hydrogen chloride, hydrogen iodide, hydrogen bromide, germane, ammonia, stibine, hydrogen sulfide, hydrogen selenide, hydrogen telluride, and NF_3 .

9. Apparatus according to claim 1, wherein the sorbate gas is boron trifluoride.

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10. An adsorption-desorption apparatus, for storage and dispensing of a gas, said apparatus comprising:

5 a storage and dispensing vessel constructed and arranged for holding a solid-phase physical sorbent medium, and for selectively flowing gas into and out of said vessel;

10 a solid-phase physical sorbent medium disposed in said storage and dispensing vessel at an interior gas pressure;

a sorbate gas physically adsorbed on said solid-phase physical sorbent medium;

15 a dispensing assembly coupled in gas flow communication with the storage and dispensing vessel, and constructed and arranged to provide, exteriorly of said storage and dispensing vessel, a pressure below said interior pressure, to effect desorption of at least a portion of said sorbate gas from the solid-phase physical sorbent medium and yield desorbed gas, and gas flow of said desorbed gas through the
20 dispensing assembly;

wherein the solid-phase physical sorbent medium concentration of trace components selected from the group consisting of water, metals, and oxidic transition metal species, based on the weight of the physical
25 sorbent medium, is insufficient to cause decomposition of the sorbate gas resulting in more than a 5% rise in interior pressure after 1 week at 25°C in said storage and dispensing vessel.

30 11. Apparatus according to claim 10, wherein the solid-phase physical sorbent medium contains less than 350 parts-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

12. Apparatus according to claim 10, wherein the solid-phase physical sorbent medium contains less than 100 parts-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

13. Apparatus according to claim 10, wherein the solid-phase physical sorbent medium contains no more than 1 part-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

14. Apparatus according to claim 10, wherein the solid-phase physical sorbent medium concentration of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium, is insufficient to decompose more than 5% by weight of the sorbate gas after 1 year at 25°C and said interior pressure, in said storage and dispensing vessel.

15. Apparatus according to claim 10, wherein the oxidic transition metal species are selected from the group consisting of oxides, sulfites and nitrates.

16. Apparatus according to claim 10, wherein the sorbate gas is a hydride gas.

17. Apparatus according to claim 10, wherein the sorbate gas is selected from the group consisting of silane, diborane, arsine, phosphine, chlorine, BCl_3 , BF_3 , B_2D_6 , tungsten hexafluoride, $(\text{CH}_3)_3\text{Sb}$, hydrogen fluoride, hydrogen chloride, hydrogen iodide, hydrogen bromide, germane, ammonia, stibine, hydrogen sulfide, hydrogen selenide, hydrogen telluride, and NF_3 .

18. Apparatus according to claim 10, wherein the sorbate gas is boron trifluoride.

19. An adsorption-desorption apparatus, for storage and
5 dispensing of boron trifluoride, said apparatus comprising:

a storage and dispensing vessel constructed and arranged for holding a solid-phase physical sorbent medium having a sorptive affinity for boron trifluoride, and for selectively flowing boron trifluoride into and
10 out of said vessel;

a solid-phase physical sorbent medium having a sorptive affinity for boron trifluoride, disposed in said storage and dispensing vessel at an interior gas pressure;

15 boron trifluoride gas, physically adsorbed on said solid-phase physical sorbent medium; and

a dispensing assembly coupled in gas flow communication with
20 the storage and dispensing vessel, and constructed and arranged to provide, exteriorly of said storage and dispensing vessel, a pressure below said interior pressure, to effect desorption of at least a portion of said boron trifluoride gas from the solid-phase physical sorbent medium to yield desorbed boron trifluoride, and gas flow of said desorbed boron
25 trifluoride gas through the dispensing assembly.

20. Apparatus according to claim 1, further comprising a heater operatively arranged in relation to the storage and dispensing vessel for selective heating of the solid-phase physical sorbent medium,
30 to effect thermally-enhanced desorption of the sorbate gas from the solid-phase physical sorbent medium.

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21. Apparatus according to claim 1, wherein the solid-phase physical sorbent medium comprises a material selected from the group consisting of silica, carbon, molecular sieves, alumina, macroreticulate polymers, kieselguhr, and aluminosilicates.

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22. Apparatus according to claim 1, wherein the solid-phase physical sorbent medium comprises a crystalline aluminosilicate composition.

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23. Apparatus according to claim 22, wherein the crystalline aluminosilicate composition has a pore size in the range of from about 4 to about 13 Angstroms.

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24. Apparatus according to claim 22, wherein the crystalline aluminosilicate composition comprises 5A molecular sieve.

25. Apparatus according to claim 22, wherein the crystalline aluminosilicate composition comprises a binderless molecular sieve.

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26. Apparatus according to claim 1, wherein the solid-phase physical sorbent medium is present in said storage and dispensing vessel with a chemisorbent material having a sorptive affinity for contaminants of said sorbate gas therein.

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27. Apparatus according to claim 26, wherein the chemisorbent material has a sorptive affinity for non-inert atmospheric gases.

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28. Apparatus according to claim 26, wherein the chemisorbent material comprises a scavenger selected from the group consisting of:

(A) a scavenger including a support having associated therewith, but not covalently bonded thereto, a compound which in the presence of said contaminant provides an anion which is reactive to

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effect the removal of said contaminant, said compound being selected from one or more members of the group consisting of:

5 (i) carbanion source compounds whose corresponding protonated carbanion compounds have a pK_a value of from about 22 to about 36; and

(ii) anion source compounds formed by reaction of said carbanion source compounds with the sorbate gas; and

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(B) a scavenger comprising:

15 (i) an inert support having a surface area in the range of from about 50 to about 1000 square meters per gram, and thermally stable up to at least about 250°C; and

20 (ii) an active scavenging species, present on the support at a concentration of from about 0.01 to about 1.0 moles per liter of support, and formed by the deposition on the support of a Group IA metal selected from sodium, potassium, rubidium, and cesium and their mixtures and alloys and pyrolysis thereof on said support.

25 29. Apparatus according to claim 26, wherein the chemisorbent material is selected from the group consisting of potassium arsenide and trityllithium.

30 30. An ion implantation system, comprising a reagent source for reagent source material and an ion implantation apparatus coupled in gas flow communication with said reagent source, and wherein the reagent source comprises:

an adsorption-desorption apparatus, for storage and dispensing of a gas, said apparatus comprising:

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a storage and dispensing vessel constructed and arranged for holding a solid-phase physical sorbent medium, and for selectively flowing gas into and out of said vessel;

5 a solid-phase physical sorbent medium disposed in said storage and dispensing vessel at an interior gas pressure;

a sorbate gas physically adsorbed on said solid-phase physical sorbent medium; and

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a dispensing assembly interconnecting the storage and dispensing vessel and said ion implantation apparatus in gas flow communication with one another, and constructed and arranged to provide, exteriorly of said storage and dispensing vessel, a pressure
15 below said interior pressure, to effect desorption of at least a portion of said sorbate gas from the solid-phase physical sorbent medium and yield desorbed gas, and gas flow of said desorbed gas through the dispensing assembly to the ion implantation apparatus;

20 wherein the solid-phase physical sorbent medium is devoid of trace components selected from the group consisting of water, metals and oxidic transition metal species in a sufficient concentration to decompose the sorbate gas in said storage and dispensing vessel.

25 31. A process for supplying a gas, comprising:

providing a storage and dispensing vessel containing a solid-phase physical sorbent medium having a physically sorptive affinity for said gas;

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physically sorptively loading said gas on said solid-phase physical sorbent medium as a sorbate gas, to yield a sorbate gas-loaded physical sorbent medium; and

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selectively desorbing at least a portion of said sorbate gas from the sorbate gas-loaded physical sorbent medium, by reduced pressure desorption, for dispensing thereof;

5 wherein any water, metals, and oxidic transition metal species present on the solid-phase physical sorbent medium are at a concentration which is insufficient to decompose more than 5% by weight of the sorbate gas in said storage and dispensing vessel after 1 year at 25°C at said interior gas pressure.

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32. A process according to claim 31, wherein the solid-phase physical sorbent medium contains less than 350 parts-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical
15 sorbent medium.

33. A process according to claim 31, wherein the solid-phase physical sorbent medium contains less than 100 parts-per-million by weight of trace components selected from the group consisting of water
20 and oxidic transition metal species, based on the weight of the physical sorbent medium.

34. A process according to claim 31, wherein the solid-phase physical sorbent medium contains no more than 1 part-per-million by
25 weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

35. A process according to claim 31, wherein the solid-phase
30 physical sorbent medium concentration of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium, is insufficient to cause decomposition of the sorbate gas resulting in more than 25% rise in interior pressure after 1 week at 25°C in said storage and dispensing
35 vessel.

36. A process according to claim 31, wherein the oxidic transition metal species are selected from the group consisting of oxides, sulfites and nitrates.

5 37. A process according to claim 31, wherein the sorbate gas is a hydride gas.

10 38. A process according to claim 31, wherein the sorbate gas is selected from the group consisting of silane, diborane, arsine, phosphine, chlorine, BCl_3 , BF_3 , B_2D_6 , tungsten hexafluoride, $(\text{CH}_3)_3\text{Sb}$, hydrogen fluoride, hydrogen chloride, hydrogen iodide, hydrogen bromide, germane, ammonia, stibine, hydrogen sulfide, hydrogen selenide, hydrogen telluride, and NF_3 .

15 39. A process according to claim 31, wherein the sorbate gas is boron trifluoride.

40. A process for supplying a gas, comprising:

20 providing a storage and dispensing vessel containing a solid-phase physical sorbent medium having a physically sorptive affinity for said gas;

25 physically sorptively loading said gas on said solid-phase physical sorbent medium as a sorbate gas, to yield a sorbate gas-loaded physical sorbent medium; and

30 selectively desorbing at least a portion of said sorbate gas from the sorbate gas-loaded physical sorbent medium, by reduced pressure desorption, for dispensing thereof;

 wherein the solid-phase physical sorbent medium concentration of trace components selected from the group consisting of water, metals, and oxidic transition metal species, based on the weight of the physical

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sorbent medium, is insufficient to cause decomposition of the sorbate gas resulting in more than a 10% rise in interior pressure after 1 week at 25°C in said storage and dispensing vessel.

5 41. A process according to claim 40, wherein the solid-phase physical sorbent medium contains less than 350 parts-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium.

10

 42. A process according to claim 40, wherein the solid-phase physical sorbent medium contains less than 100 parts-per-million by weight of trace components selected from the group consisting of water and oxidic transition metal species, based on the weight of the physical
15 sorbent medium.

 43. A process according to claim 40, wherein the solid-phase physical sorbent medium contains no more than 1 part-per-million by weight of trace components selected from the group consisting of water
20 and oxidic transition metal species, based on the weight of the physical sorbent medium.

 44. A process according to claim 40, wherein the solid-phase physical sorbent medium concentration of trace components selected
25 from the group consisting of water and oxidic transition metal species, based on the weight of the physical sorbent medium, is insufficient to decompose more than 5% by weight of the sorbate gas after 1 year at 25°C and said interior pressure, in said storage and dispensing vessel.

30 45. A process according to claim 40, wherein the oxidic transition metal species are selected from the group consisting of oxides, sulfites and nitrates.

 46. A process according to claim 40, wherein the sorbate gas
35 is a hydride gas.

47. A process according to claim 40, wherein the sorbate gas is selected from the group consisting of silane, diborane, arsine, phosphine, chlorine, BCl_3 , BF_3 , B_2D_6 , tungsten hexafluoride, $(\text{CH}_3)_3\text{Sb}$, hydrogen fluoride, hydrogen chloride, hydrogen iodide, hydrogen bromide, germane, ammonia, stibine, hydrogen sulfide, hydrogen selenide, hydrogen telluride, and NF_3 .

48. A process according to claim 40, wherein the sorbate gas is boron trifluoride.

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49. An adsorption-desorption process for storage and dispensing of boron trifluoride, said process comprising:

providing a storage and dispensing vessel containing a solid-phase physical sorbent medium having a physically sorptive affinity for boron trifluoride;

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physically sorptively loading boron trifluoride on said solid-phase physical sorbent medium, to yield a boron trifluoride-loaded physical sorbent medium; and

20

selectively desorbing at least a portion of said boron trifluoride from the boron trifluoride-loaded physical sorbent medium, by reduced pressure desorption, for dispensing thereof.

25

50. A process according to claim 31, further comprising selectively heating the solid-phase physical sorbent medium, to effect thermally-enhanced desorption of the sorbate gas from the solid-phase physical sorbent medium.

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51. A process according to claim 31, wherein the solid-phase physical sorbent medium comprises a material selected from the group consisting of silica, carbon molecular sieves, alumina, macroreticulate polymers, kieselguhr, carbon, and aluminosilicates.

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52. A process according to claim 31, wherein the solid-phase physical sorbent medium comprises a crystalline aluminosilicate composition.

5 53. A process according to claim 52, wherein the crystalline aluminosilicate composition has pore size in the range of from about 4 to about 13 Angstroms.

10 54. A process according to claim 52, wherein the crystalline aluminosilicate composition comprises 5A molecular sieve.

55. A process according to claim 52, wherein the crystalline aluminosilicate composition comprises a binderless molecular sieve.

15 56. A process according to claim 31, wherein the solid-phase physical sorbent medium is present in said storage and dispensing vessel with a chemisorbent material having a sorptive affinity for contaminants of said sorbate gas therein.

20 57. A process according to claim 31, wherein the sorbate gas comprises an impurity component, and the solid-phase physical sorbent medium is provided in the storage and dispensing vessel together with an impurity scavenger for removal of the impurity component from the sorbate gas.

25

58. A process according to claim 56, wherein the chemisorbent material has a sorptive affinity for non-inert atmospheric gases.

30 59. A process according to claim 56, wherein the chemisorbent material comprises a scavenger selected from the group consisting of:

(A) a scavenger including a support having associated therewith, but not covalently bonded thereto, a compound which in the presence of said contaminant provides an anion which is reactive to

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effect the removal of said contaminant, said compound being selected from one or more members of the group consisting of:

5 (i) carbanion source compounds whose corresponding protonated carbanion compounds have a pK_a value of from about 22 to about 36; and

(ii) anion source compounds formed by reaction of said carbanion source compounds with the sorbate gas; and

10

(B) a scavenger comprising:

15 (i) an inert support having a surface area in the range of from about 50 to about 1000 square meters per gram, and thermally stable up to at least about 250°C; and

20 (ii) an active scavenging species, present on the support at a concentration of from about 0.01 to about 1.0 moles per liter of support, and formed by the deposition on the support of a Group IA metal selected from sodium, potassium, rubidium, and cesium and their mixtures and alloys and pyrolysis thereof on said support.

25 60. A process according to claim 56, wherein the chemisorbent material is selected from the group consisting of potassium arsenide and trityllithium.

30 61. An adsorption-desorption apparatus, for storage and dispensing of a gas sorbable on a solid-phase physical sorbent medium, said apparatus comprising:

a storage and dispensing vessel constructed and arranged for holding a solid-phase physical sorbent medium, and for selectively flowing gas into and out of said vessel;

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a solid-phase physical sorbent medium disposed in said storage and dispensing vessel at an interior gas pressure;

5 a sorbate gas physically adsorbed on said solid-phase physical sorbent medium;

10 a dispensing assembly coupled in gas flow communication with the storage and dispensing vessel, and constructed and arranged to provide, exteriorly of said storage and dispensing vessel, a pressure below said interior pressure, to effect desorption of at least a portion of said sorbate gas from the solid-phase physical sorbent medium and yield desorbed gas, and gas flow of said desorbed gas through the dispensing assembly;

15 a cryopump coupled to said dispensing assembly for pressurizing the desorbed gas and discharging the pressurized gas.

20 62. A process for storage and dispensing of a gas sorbable on a solid-phase physical sorbent medium, said process comprising:

providing a storage and dispensing vessel holding a solid-phase physical sorbent medium;

25 adsorbing said gas on said solid-phase physical sorbent medium to yield said gas adsorbed on said solid-phase physical sorbent medium, at an interior pressure in said storage and dispensing vessel;

30 establishing, exteriorly of said storage and dispensing vessel, a pressure below said interior pressure, to effect desorption of at least a portion of said gas from the solid-phase physical sorbent medium as desorbed gas, and flowing said desorbed gas out of the storage and dispensing vessel;

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cryopumping the desorbed gas from the storage and dispensing vessel to a predetermined pressure, wherein said predetermined pressure is higher than the pressure of the desorbed gas flowed out of the storage and dispensing vessel.

5 63. An adsorption/desorption apparatus for storage and dispensing of gas, said apparatus comprising:

a storage and dispensing vessel holding a solid-phase physical sorbent medium and a gas sorbed on the physical sorbent medium;

10 a dispensing assembly coupled in gas flow communication with the storage and dispensing vessel and arranged for discharging from the vessel gas desorbed from the physical sorbent medium, wherein the dispensing assembly is constructed and arranged to provide pressure conditions effecting desorption of the gas sorbed on the physical sorbent medium, without heating of the physical sorbent medium.

15 64. An adsorption/desorption apparatus for storage and dispensing of gas, said apparatus comprising:

20 a storage and dispensing vessel holding a solid-phase physical sorbent medium, and a gas physically adsorbed on the physical sorbent medium, wherein said gas when decomposed forms a gaseous contaminant of the gas that is physically adsorbed on the physical sorbent medium;

a dispensing assembly for flowing gas desorbed from the physical sorbent medium out of the vessel for dispensing thereof; and

25 a chemisorbent material in the vessel for chemisorbing the gaseous contaminant resulting from decomposition of said gas, whereby desorbed gas dispensed by the dispensing assembly from the vessel is free of said gaseous contaminant.

65. An adsorption/desorption apparatus for storage and dispensing of gas, said apparatus comprising:

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a storage and dispensing vessel holding a solid-phase physical sorbent medium with a gas sorbed thereon, wherein the physical sorbent medium is a non-zeolite material;

5 a dispensing assembly for selectively discharging gas from the vessel; and

10 a pump coupled in gas flow communication with the dispensing assembly and arranged to pump gas from the vessel so that the gas is desorbed from the solid-phase physical sorbent medium and flowed through the dispensing assembly.

66. Apparatus according to claim 1, wherein the dispensing assembly is coupled in gas flow communication with a semiconductor material or semiconductor device manufacturing apparatus that utilizes the gas for manufacture of the semiconductor material or semiconductor device.

67. A process according to claim 31, wherein gas desorbed from the sorbate gas-loaded physical sorbent medium is employed for manufacturing a semiconductor material or semiconductor device.

68. A method according to claim 67, wherein the gas is utilized in ion implantation for manufacturing said semiconductor material or semiconductor device.

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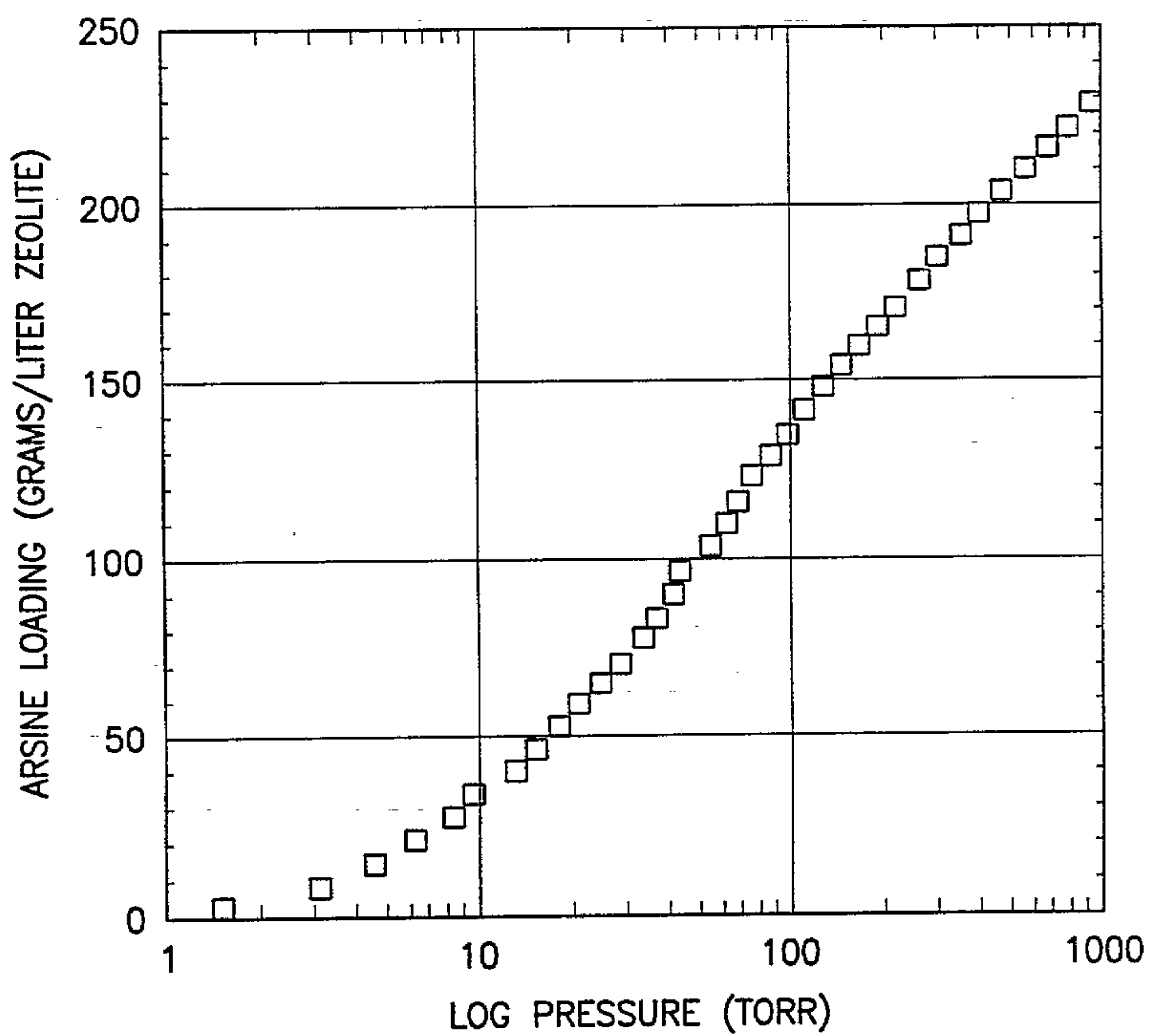


FIG. 1

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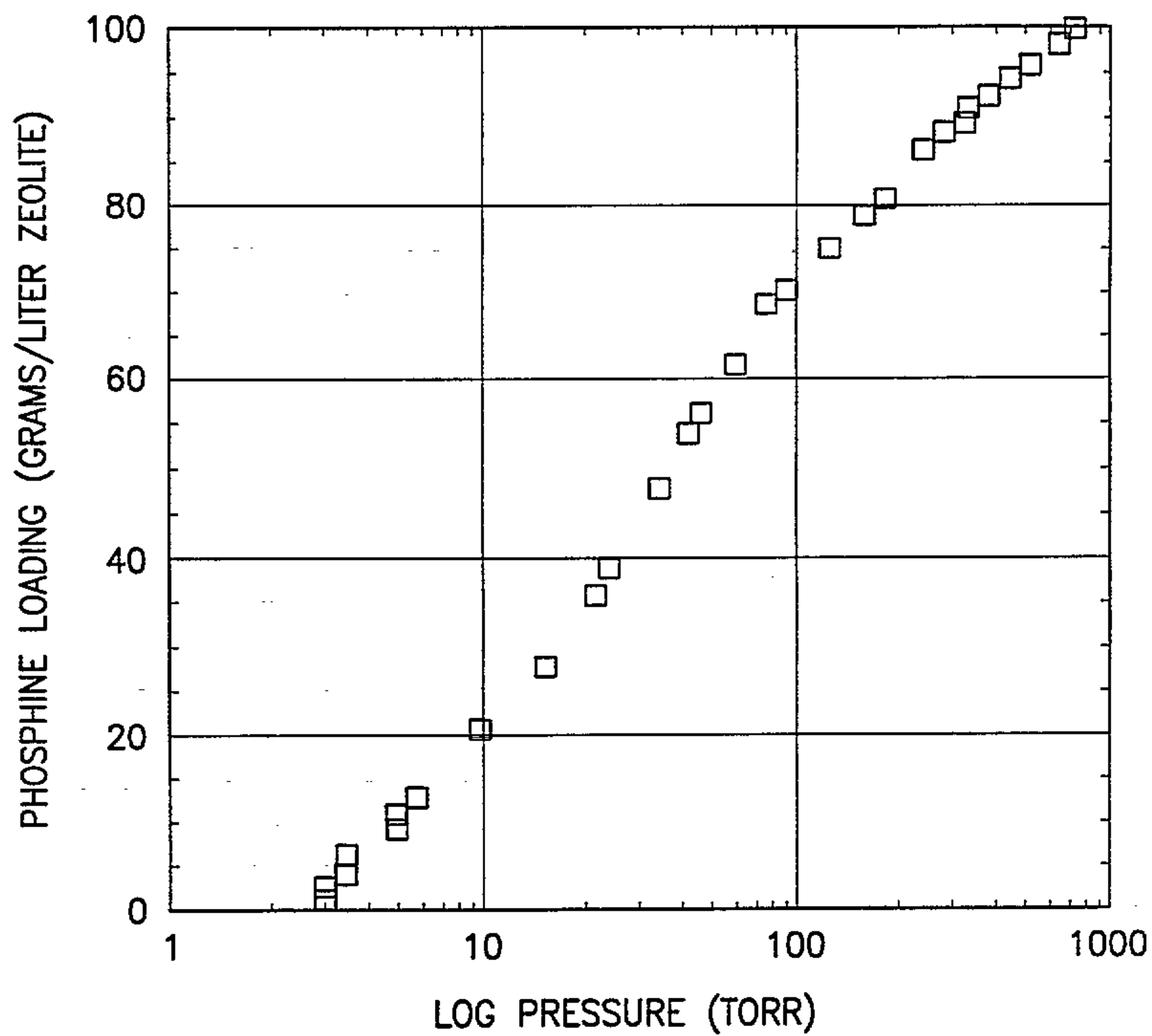
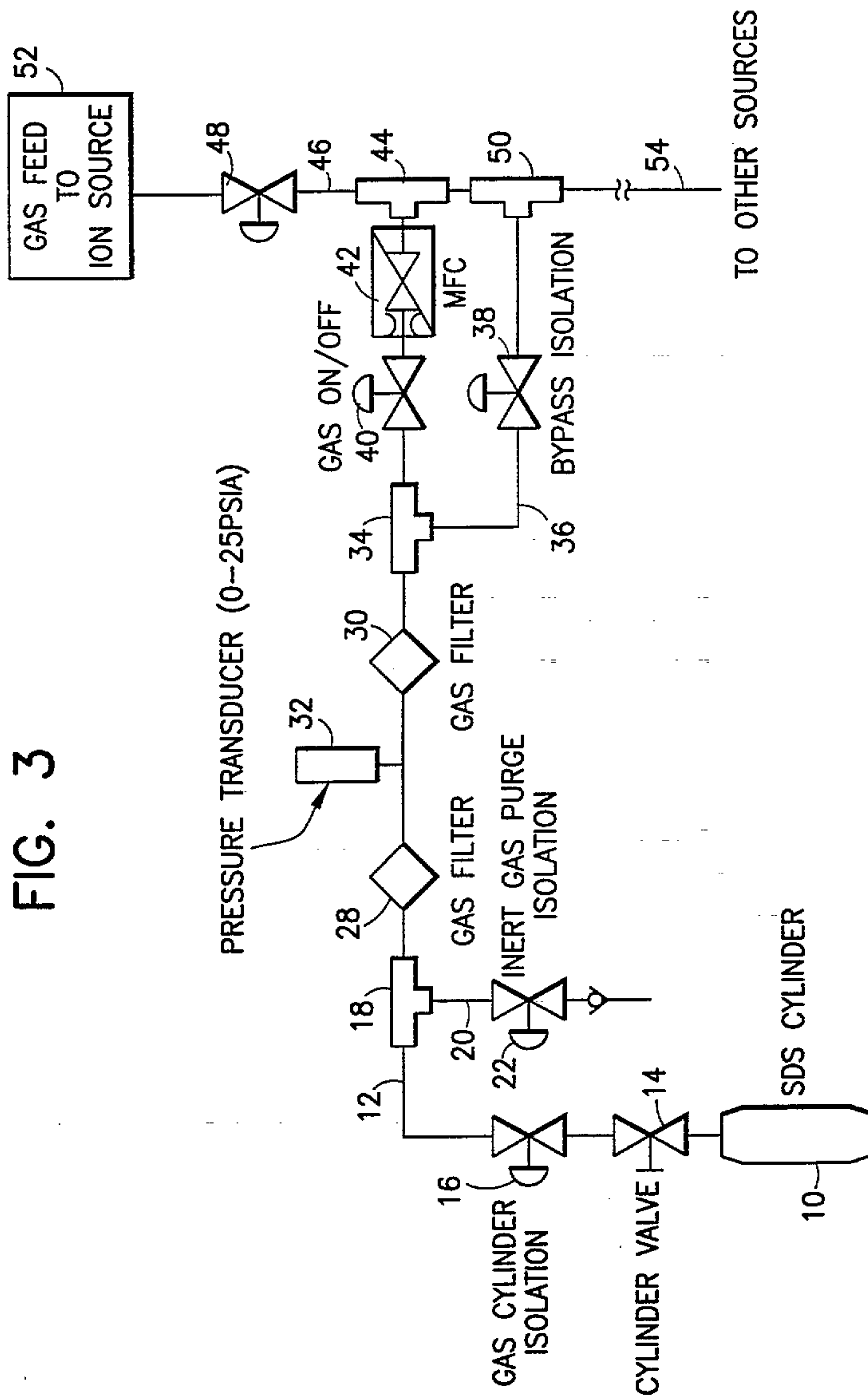


FIG. 2

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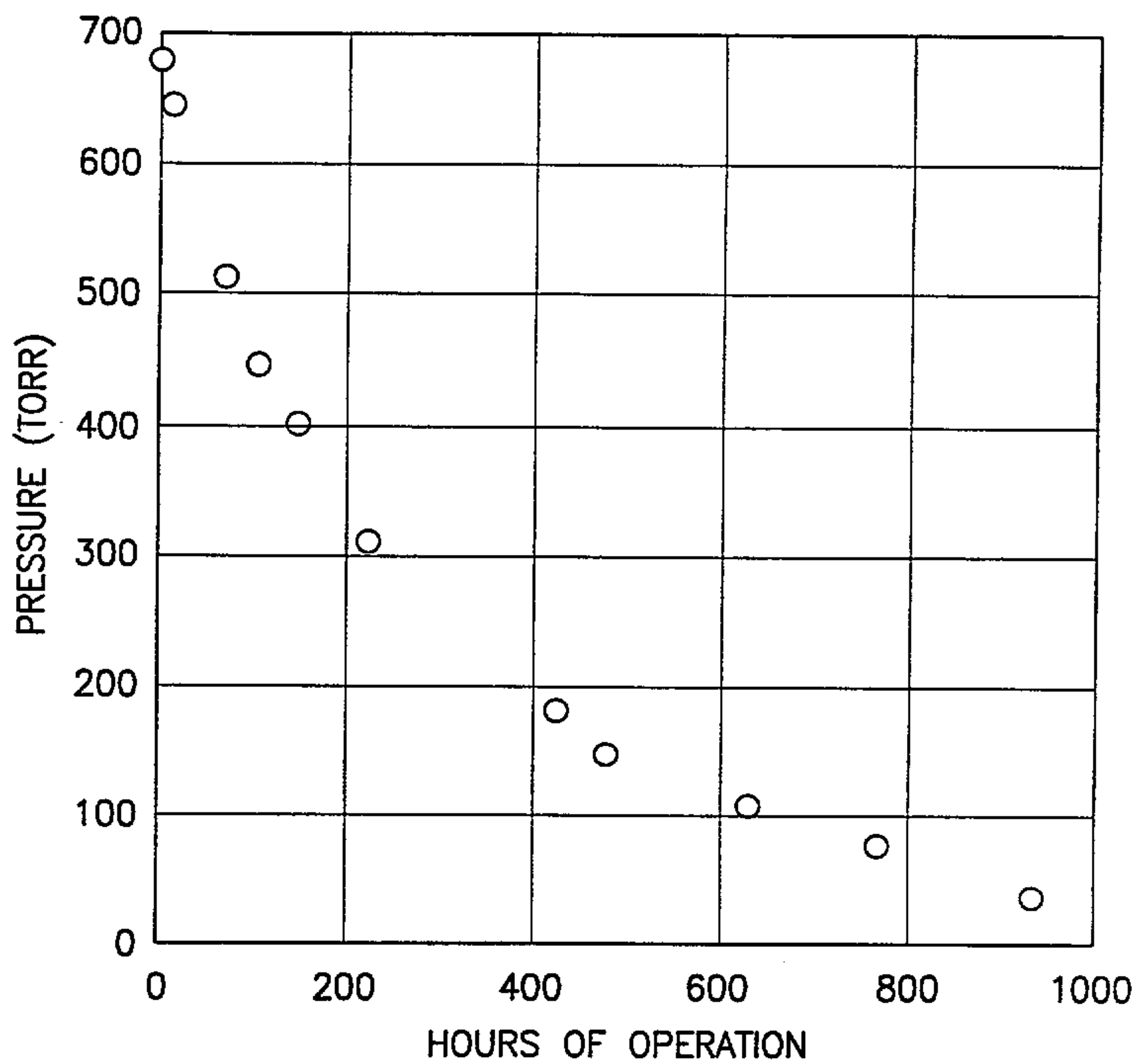


FIG. 4

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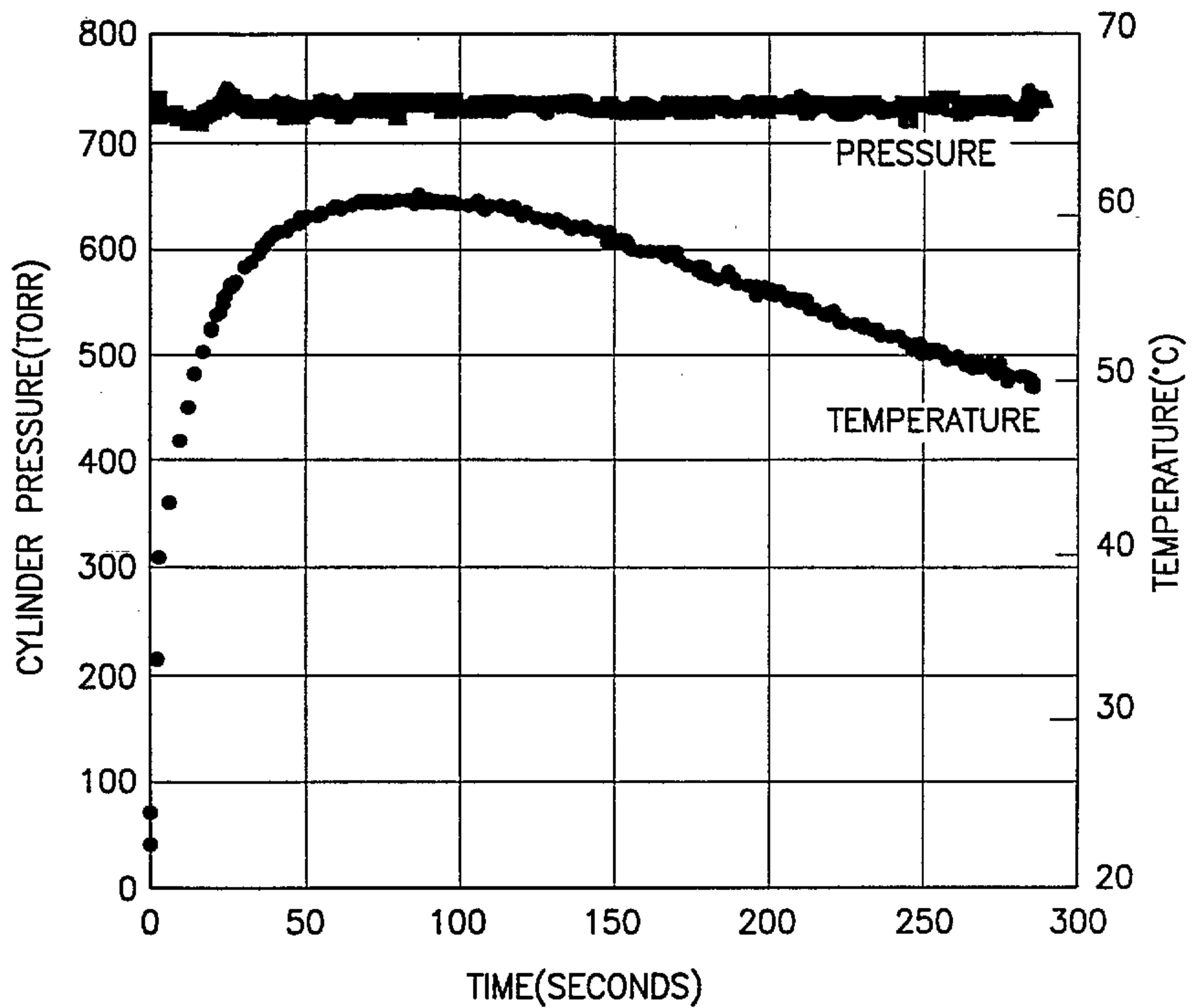


FIG. 5

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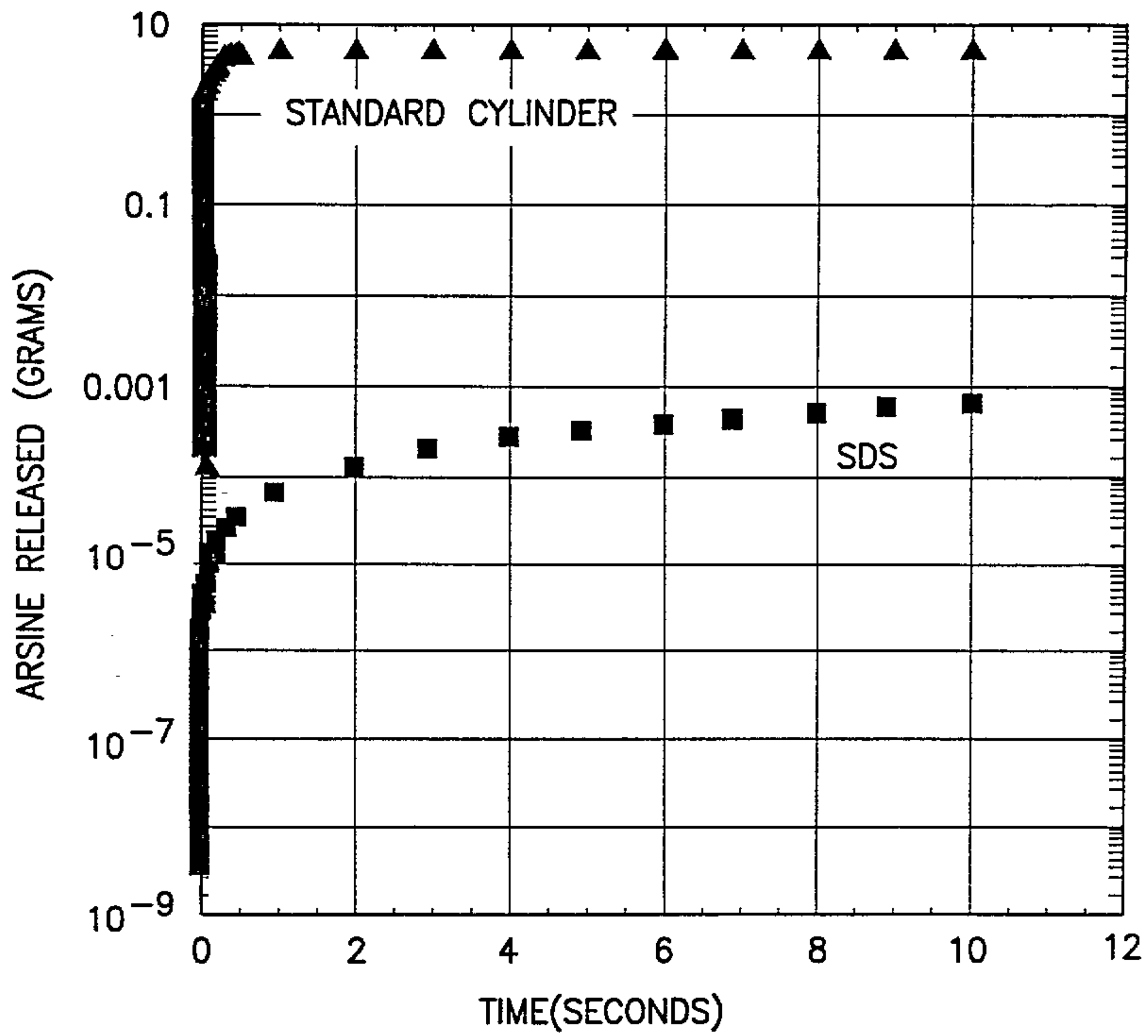


FIG. 6

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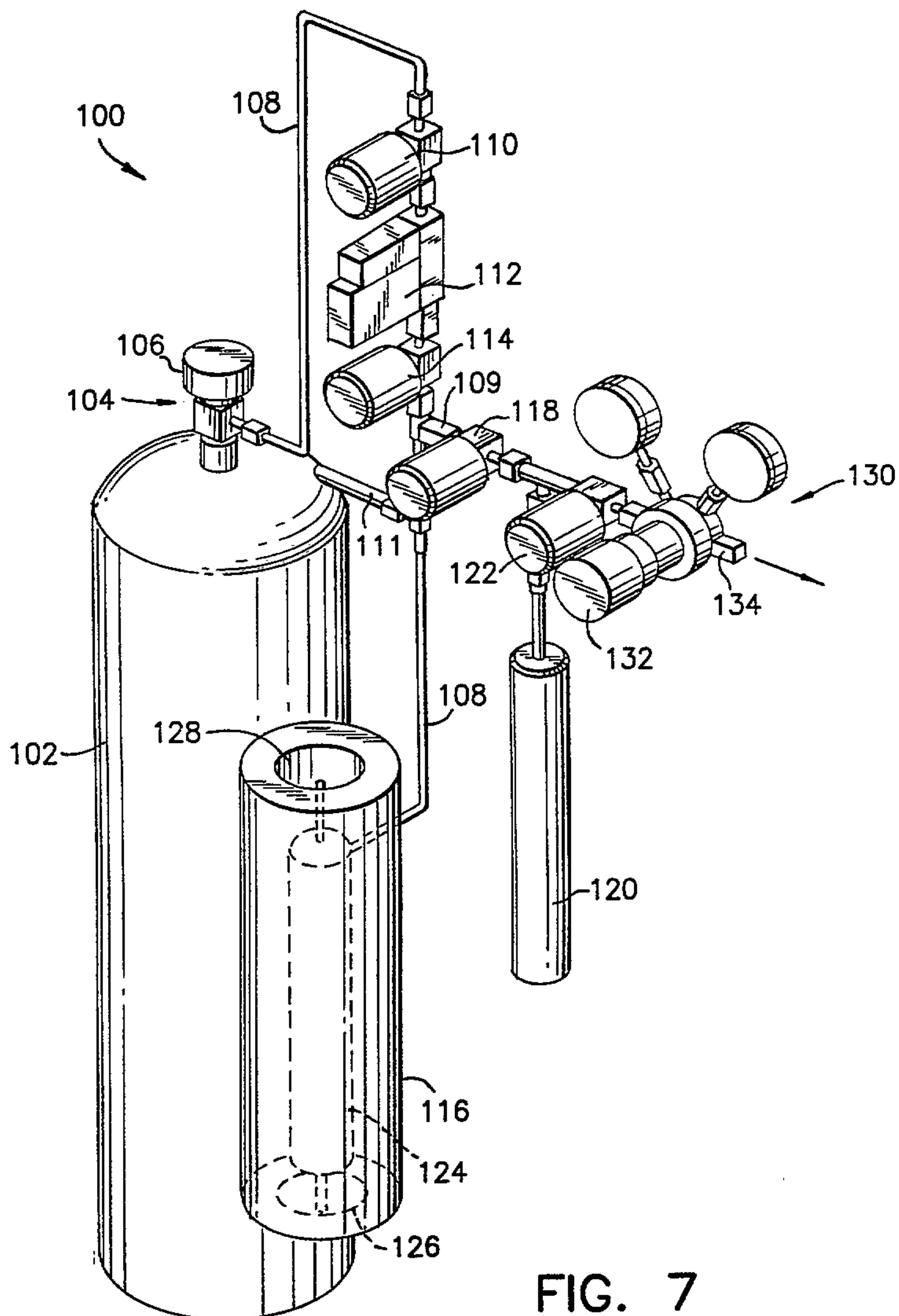


FIG. 7

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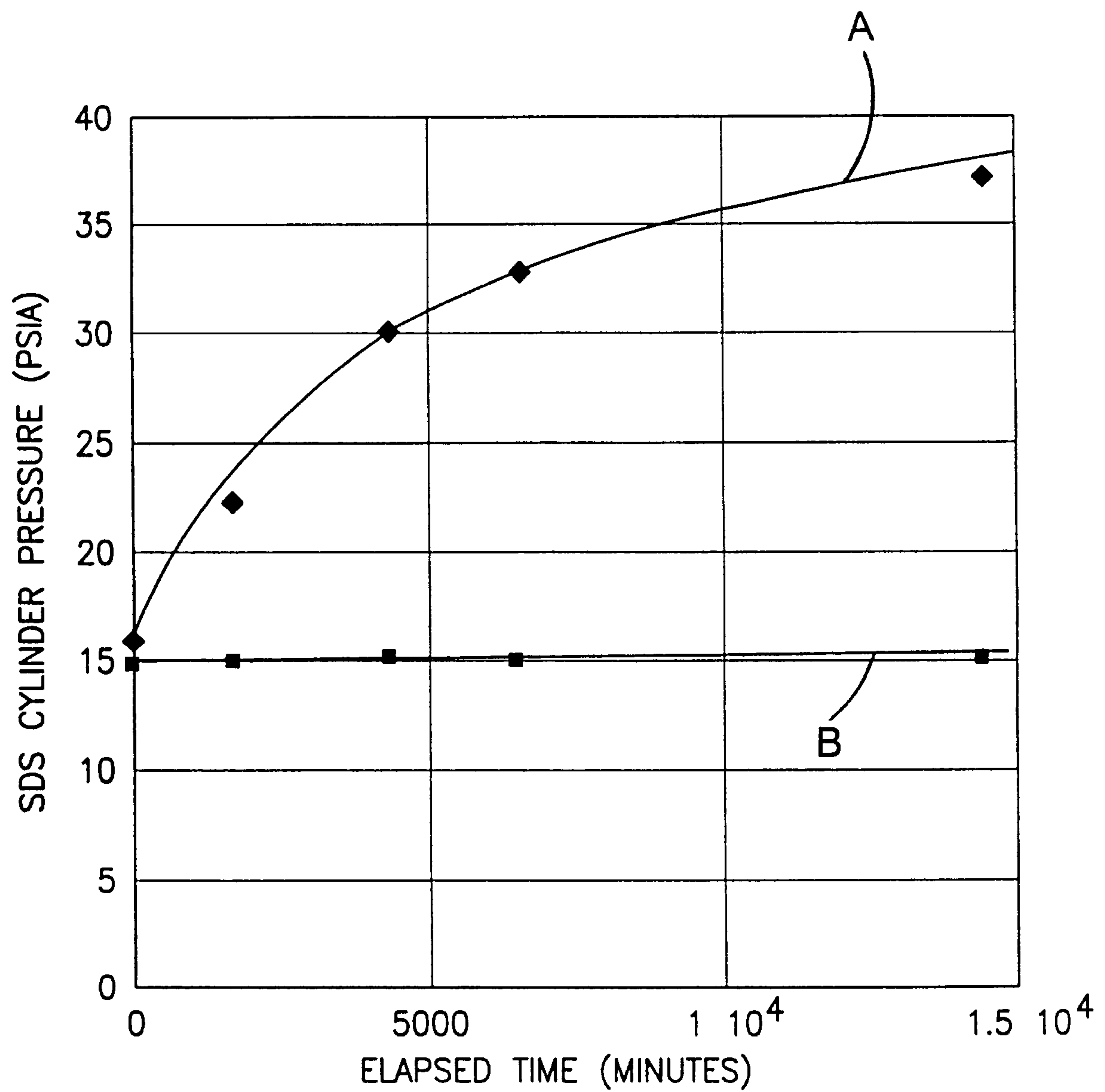


FIG. 8

